

## QUICKSWITCH<sup>®</sup> PRODUCTS HIGH-SPEED CMOS QUICKSWITCH 8-BIT BUS SWITCH

### **FEATURES**:

- · Enhanced N channel FET with no inherent diode to Vcc
- 5 $\Omega$  bidirectional switches connect inputs to outputs
- Pin compatible with the 74F245, 74FCT245, and 74FCT245T
- · Low power CMOS proprietary technology
- · Zero propagation delay, zero ground bounce
- · Undershoot clamp diodes on all switch and control inputs
- · TTL-compatible control inputs
- Available in SOIC and QSOP packages

#### **DESCRIPTION:**

The QS3245 provides a set of eight high-speed CMOS TTL-compatible bus switches in a pinout compatible with 74FCT245, 74F245, 74ALS/AS/ LS245 8-bit transceivers. The low ON resistance of the QS3245 allows inputs to be connected to outputs without adding propagation delay and without generating additional ground bounce noise. The Output Enable  $(\overline{OE})$  signal turns the switches on similar to the  $\overline{OE}$  signal of the 74'245.

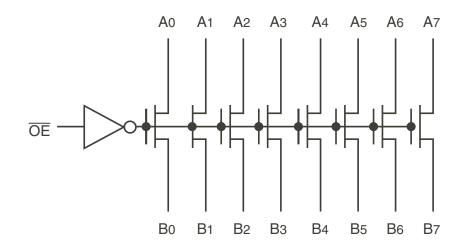
QuickSwitch devices provide an order of magnitude faster speed than conventional logic devices.

The QS3245 is characterized for operation at -40°C to +85°C.

#### **APPLICATIONS:**

- · Hot-swapping, hot-docking
- Voltage translation (5V to 3.3V)
- · Power conservation
- Capacitance reduction and isolation
- · Logic replacement (data processing)
- Clock gating
- Bus switching and isolation

## FUNCTIONAL BLOCK DIAGRAM

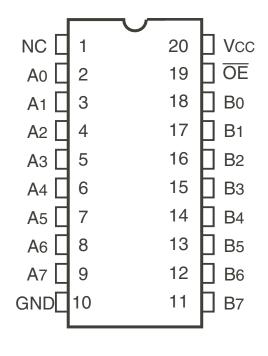


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#### INDUSTRIAL TEMPERATURE RANGE

#### **NOVEMBER 2014**

### **PINCONFIGURATION**



SOIC/ QSOP TOP VIEW

#### ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

Symbol	Description	Max	Unit
VTERM <sup>(2)</sup>	Supply Voltage to Ground	–0.5 to +7	V
VTERM <sup>(3)</sup>	DC Switch Voltage Vs	–0.5 to +7	V
VTERM <sup>(3)</sup>	DC Input Voltage VIN	-0.5 to +7	V
VAC	AC Input Voltage (pulse width $\leq$ 20ns)	-3	V
Ιουτ	DC Output Current	120	mA
Рмах	Maximum Power Dissipation (TA = 85°C)	0.5	W
Tstg	Storage Temperature	-65 to +150	°C

NOTE:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

2. Vcc terminals.

3. All terminals except Vcc.

### CAPACITANCE

(TA = +25°C, f = 1.0MHz, VIN = 0V, VOUT = 0V)

Pins	Тур.	Max. <sup>(1)</sup>	Unit
Control Pins	3	5	pF
Quickswitch Channels (Switch OFF)	5	7	pF

NOTE:

1. This parameter is measured at characterization but not tested.

### **PINDESCRIPTION**

Pin Names	Description		
ŌĒ	OutputEnable		
Ax	Data I/Os		
Bx	Data I/Os		

### **FUNCTION TABLE(1)**

ŌĒ	Outputs		
Н	Disconnected		
L	Ax = Bx		

NOTE:

1. H = HIGH Voltage Level

L = LOW Voltage Level

## DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified: Industrial: TA = -40°C to +85°C, Vcc =  $5.0V \pm 5\%$ 

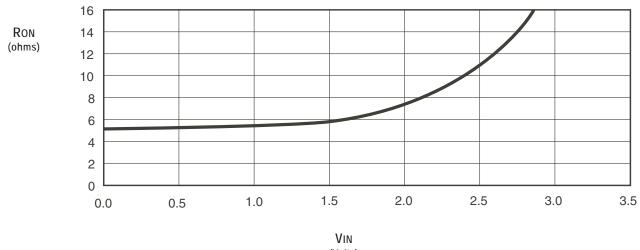
Symbol	Parameter	Test Conditions	Min.	Typ. <sup>(1)</sup>	Max.	Unit
Vih	Input HIGH Level	Guaranteed Logic HIGH for Control Pins	2	—	—	V
VIL	Input LOW Level	Guaranteed Logic LOW for Control Pins	_	—	0.8	V
lin	Input LeakageCurrent (Control Inputs)	$0V \le VIN \le VCC$	_	—	±1	μA
loz	Off-State Output Current (Hi-Z)	$0V \le VOUT \le Vcc$ , Switches OFF	_	±0.001	±1	μA
Ron	Switch ON Resistance	Vcc = Min., VIN = 0V, ION = 30mA	_	5	7	Ω
		Vcc = Min., VIN = 2.4V, ION =15mA	_	10	15	
Vp	Pass Voltage <sup>(2)</sup>	$V_{IN} = V_{CC} = 5V$ , Iout = -5 $\mu$ A	3.7	4	4.2	V

NOTES:

1. Typical values are at Vcc = 5.0V, TA = 25°C.

2. Pass Voltage is guaranteed but not production tested.

### TYPICAL ON RESISTANCE vs VIN AT Vcc = 5V



(Volts)

## **POWER SUPPLY CHARACTERISTICS**

Symbol	Parameter	Test Conditions <sup>(1)</sup>	Max.	Unit
lccq	Quiescent Power Supply Current	Vcc = Max., VIN = GND or Vcc, f = 0	3	μΑ
Δlcc	Power Supply Current per Control Input HIGH (2)	Vcc = Max., VIN = 3.4V, f = 0	1.5	mA
ICCD	Dynamic Power Supply Current per MHz <sup>(3)</sup>	Vcc = Max., A and B pins open	0.25	mA/MHz
		Control Inputs Toggling at 50% Duty Cycle		

NOTES:

1. For conditions shown as Min. or Max., use the appropriate values specified under DC Electrical Characteristics.

2. Per TLL driven input (VIN = 3.4V, control inputs only). A and B pins do not contribute to  $\Delta$ Icc.

3. This current applies to the control inputs only and represents the current required to switch internal capacitance at the specified frequency. The A and B inputs generate no significant AC or DC currents as they transition. This parameter is guaranteed but not production tested.

# SWITCHING CHARACTERISTICS OVER OPERATING RANGE

 $T_A = -40^{\circ}C$  to +85°C, Vcc = 5.0V ± 5%;

CLOAD = 50pF, RLOAD =  $500\Omega$  unless otherwise noted.

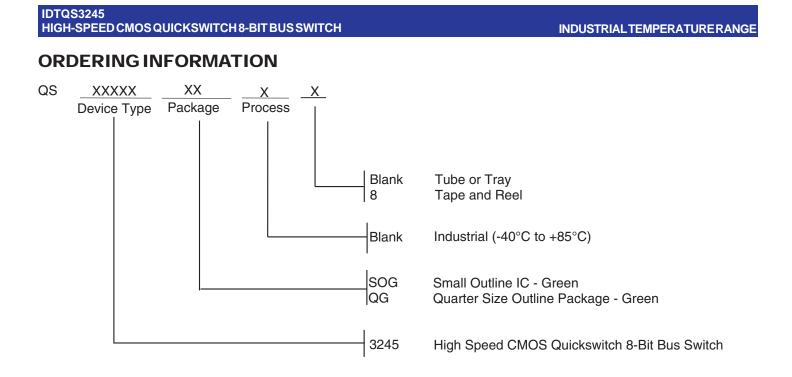
Symbol	Parameter	Min. <sup>(1)</sup>	Тур.	Max.	Unit
tPLH	Data Propagation Delay <sup>(2,3)</sup>	—	—	0.25	ns
tPHL	An to/from Bn				
tPZL	Switch Turn-on Delay	0.5	—	5.6	ns
tРZH	OE to Ax/Bx				
tPLZ	Switch Turn-off Delay <sup>(2)</sup>	0.5	_	4.5	ns
tPHZ	OE to Ax/Bx				

NOTES:

1. Minimums are guaranteed but not production tested.

2. This parameter is guaranteed but not production tested.

<sup>3.</sup> The bus switch contributes no propagation delay other than the RC delay of the ON resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.25ns for C<sub>L</sub> = 50pF. Since this time constant is much smaller than the rise and fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the bus switch, when used in a system, is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.



# **Datasheet Document History**

02/14/2011 Pg. 5 Updated the ordering information by removing the "IDT" notation, non RoHS part and by adding Tape and Reel information.

11/24/2014 Pg. 1 Corrected Functional Block Diagram adding missing dot on A1.